## **ONSEMÍ**...

### **Digital Transistors (BRT)** R1 = 2.2 k $\Omega$ , R2 = 47 k $\Omega$

PNP Transistors with Monolithic Bias Resistor Network

### MUN2135, MMUN2135L, MUN5135, DTA123JE, DTA123JM3, NSBA123JF3

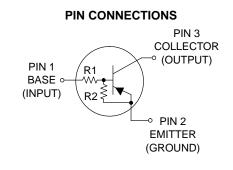
This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

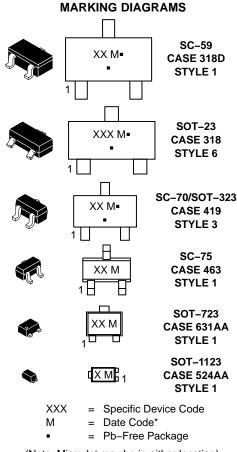
### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

<b>MAXIMUM RATINGS</b> ( $T_A = 25^{\circ}C$ )			
Rating	Symbol	Max	Unit
Collector–Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector–Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	100	mAdc
Input Forward Voltage	V <sub>IN(fwd)</sub>	12	Vdc
Input Reverse Voltage	V <sub>IN(rev)</sub>	5	Vdc

### Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.





(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet. NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

<sup>\*</sup>Date Code orientation may vary depending upon manufacturing location.

### Table 1. ORDERING INFORMATION

Device	Part Marking	Package	Shipping <sup>†</sup>
MMUN2135LT1G, NSVMMUN2135LT1G*	ACA	SOT-23 (Pb-Free)	3000 / Tape & Reel
MUN5135T1G	6M	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTA123JET1G	6M	SC–75 (Pb–Free)	3000 / Tape & Reel
NSVDTA123JM3T5G*	6M	SOT-723 (Pb-Free)	8000 / Tape & Reel

### DISCONTINUED (Note 1)

MUN2135T1G	6R	SC–59 (Pb–Free)	3000 / Tape & Reel
DTA123JM3T5G	6M	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSBA123JF3T5G	J (90°)**	SOT–1123 (Pb–Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.

\*\*(XX $^{\circ}$ ) = Degree rotation in the clockwise direction.

1. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <u>www.onsemi.com</u>.

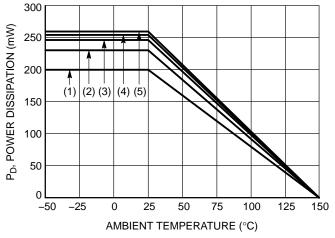


Figure 1. Derating Curve

<u>www.onsemi.com</u> 2 (1) SC-75 and SC-70/SOT323; Minimum Pad
(2) SC-59; Minimum Pad
(3) SOT-23; Minimum Pad

(4) SOT-1123; 100 mm<sup>2</sup>, 1 oz. copper trace

(5) SOT–723; Minimum Pad

### **Table 2. THERMAL CHARACTERISTICS**

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SC-59) (MUN2135)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 2) (Note 3) (Note 2)	P <sub>D</sub>	230 338 1.8	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 3) (Note 2) (Note 3)	$R_{ hetaJA}$	2.7 540 370	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{ ext{ heta}JL}$	264 287	°C/W
Junction and Storage Temperature Range	, , , , , , , , , , , , , , , , , , ,	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SOT-23) (MMUN2135L)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	(Note 2) (Note 3) (Note 2) (Note 3)	P <sub>D</sub>	246 400 2.0 3.2	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 3)	$R_{\thetaJA}$	508 311	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{\thetaJL}$	174 208	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5135)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 2) (Note 3) (Note 2) (Note 3)	P <sub>D</sub>	202 310 1.6 2.5	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{ hetaJA}$	618 403	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{\theta JL}$	280 332	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-75) (DTA123JE)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	(Note 2) (Note 3) (Note 2) (Note 3)	P <sub>D</sub>	200 300 1.6 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{\thetaJA}$	600 400	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SOT-723) (DTA123JM3)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 2) (Note 3) (Note 2) (Note 3)	P <sub>D</sub>	260 600 2.0 4.8	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{ hetaJA}$	480 205	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

FR-4 @ 1.0 x 1.0 Inch Pad.
 FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
 FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

### **Table 2. THERMAL CHARACTERISTICS**

Characteristic		Symbol	Мах	Unit
THERMAL CHARACTERISTICS (SOT-1123) (NSBA123JF3)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 4) (Note 5) (Note 4) (Note 5)	P <sub>D</sub>	254 297 2.0 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 4) (Note 5)	$R_{ hetaJA}$	493 421	°C/W
Thermal Resistance, Junction to Lead	(Note 4)	$R_{ ext{ heta}JL}$	193	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

2. FR-4 @ Minimum Pad.

3. FR-4 @ 1.0 x 1.0 Inch Pad.

FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
 FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

### Table 3. ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = $25^{\circ}$ C, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		-	-		
Collector–Base Cutoff Current $(V_{CB} = 50 \text{ V}, I_E = 0)$	I <sub>CBO</sub>	_	_	100	nAdc
Collector–Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$	I <sub>CEO</sub>	_	_	500	nAdc
Emitter–Base Cutoff Current ( $V_{EB} = 6.0 \text{ V}, I_C = 0$ )	I <sub>EBO</sub>	_	_	0.2	mAdc
Collector–Base Breakdown Voltage $(I_C = 10 \ \mu\text{A}, I_E = 0)$	V <sub>(BR)CBO</sub>	50	_	_	Vdc
Collector–Emitter Breakdown Voltage (Note 6) $(I_C = 2.0 \text{ mA}, I_B = 0)$	V <sub>(BR)CEO</sub>	50	_	_	Vdc
ON CHARACTERISTICS					
DC Current Gain (Note 5) ( $I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$ )	h <sub>FE</sub>	80	140	_	
Collector – Emitter Saturation Voltage (Note 6) $(I_C = 10 \text{ mA}, I_B = 0.3 \text{ mA})$	V <sub>CE(sat)</sub>	_	_	0.25	Vdc
Input Voltage (off) ( $V_{CE} = 5.0 \text{ V}, I_C = 100 \mu \text{A}$ )	V <sub>i(off)</sub>	_	0.6	0.5	Vdc
Input Voltage (on) (V <sub>CE</sub> = 0.3 V, I <sub>C</sub> = 5.0 mA)	V <sub>i(on)</sub>	1.1	0.8	_	Vdc
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 2.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OL</sub>	_	_	0.2	Vdc
Output Voltage (off) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OH</sub>	4.9	_	_	Vdc
Input Resistor	R1	1.5	2.2	2.9	kΩ
Resistor Ratio	R <sub>1</sub> /R <sub>2</sub>	0.038	0.047	0.056	

6. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq 2\%$ .

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS MUN2135, MMUN2135L, MUN5135, DTA123JE, DTA123JM3

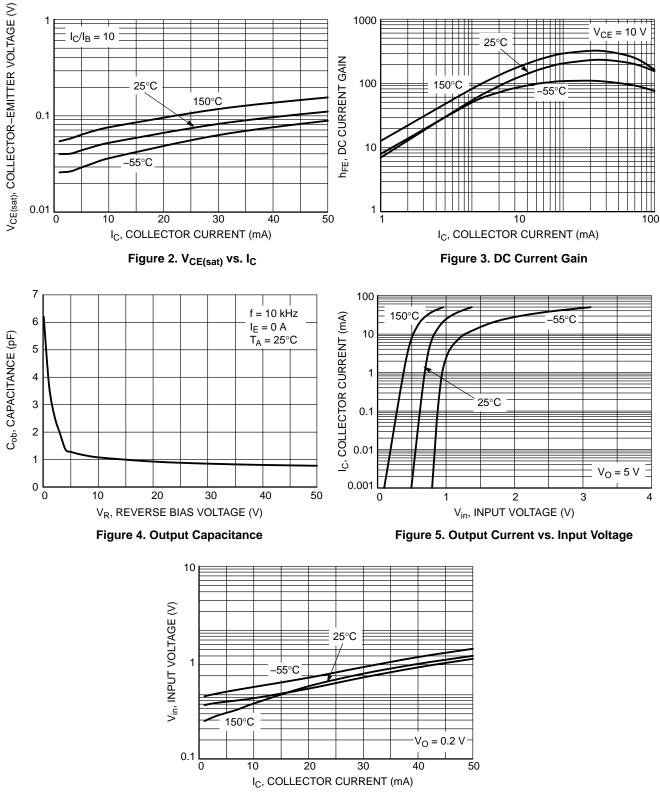
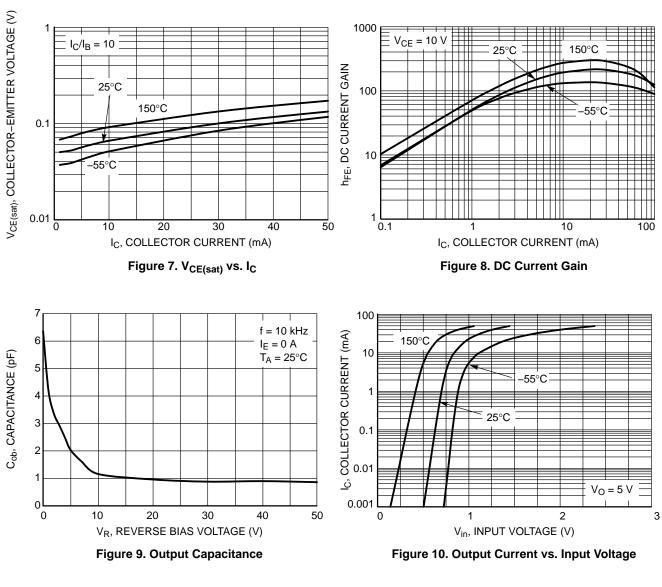
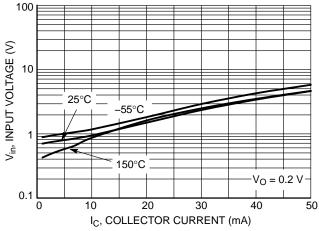


Figure 6. Input Voltage vs. Output Current



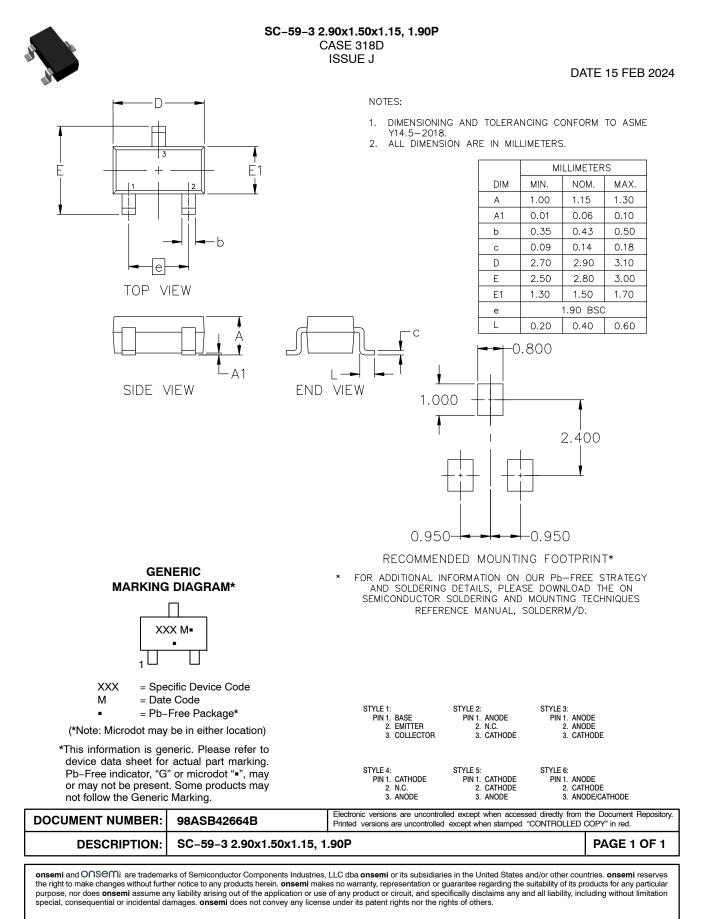
### TYPICAL CHARACTERISTICS NSBA123JF3





### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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## semi



### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

**ISSUE AU** 

DATE 14 AUG 2024









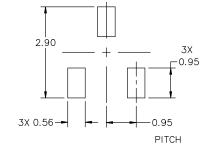




XXX = Specific Device Code М = Date Code

= Pb-Free Package .

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS					
DIM	MIN	NOM	МАХ		
А	0.89	1.00	1.11		
A1	0.01	0.06	0.10		
b	0.37	0.44	0.50		
с	0.08	0.14	0.20		
D	2.80	2.90	3.04		
E	1.20	1.30	1.40		
е	1.78	1.90	2.04		
L	0.30	0.43	0.55		
L1	0.35	0.54	0.69		
Ηe	2.10	2.40	2.64		
Т	0°		10°		

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **STYLES ON PAGE 2**

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### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CÁSE 318** ISSUE AU

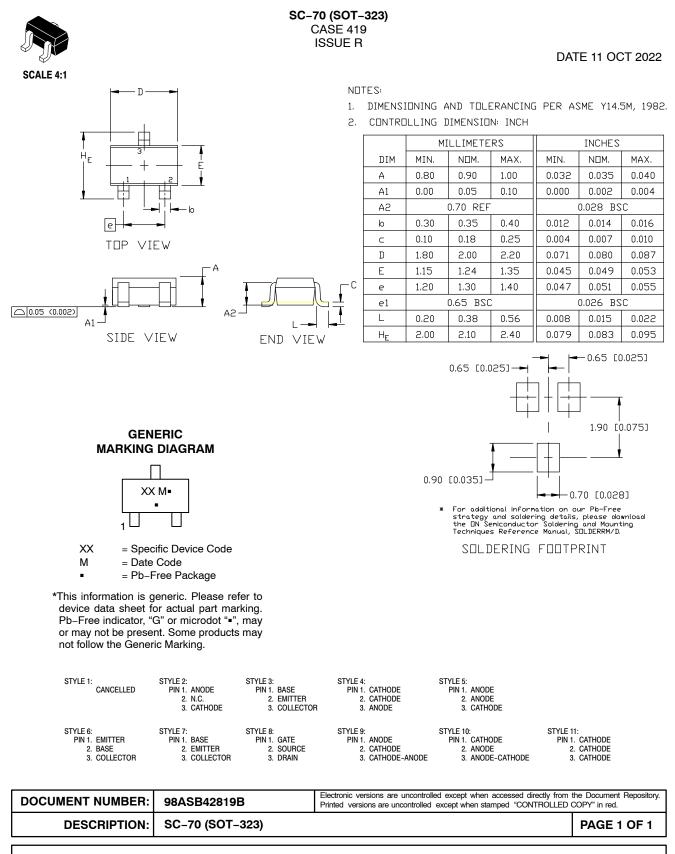
DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ı	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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DESCRIPTION: SOT-23 (TO-236) 2	SOT-23 (TO-236) 2.90x1.30x1.00 1.90P		

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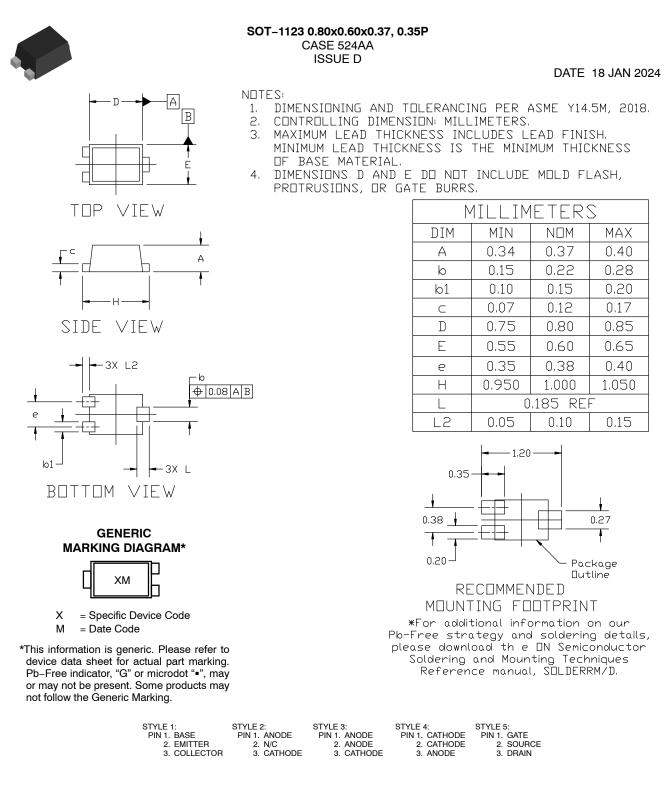
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### **MECHANICAL CASE OUTLINE** PACKAGE DIMENSIONS

#### SC75-3 1.60x0.80x0.80, 1.00P **CASE 463 ISSUE H** DATE 01 FEB 2024 NOTES: Α D DIMENSIONING AND TOLERANCING CONFORM 1. В TO ASME Y14.5-2018. ALL DIMENSION ARE IN MILLIMETERS. 2. F MILLIMETERS F DIM MIN. MAX. NOM. 0.70 0.800.90 А 3X b Α1 0.00 0.05 0.10 $\oplus$ 0.20 $\oplus$ C A B е A2 0.80 REF. 0.15 0.20 b 0.30 TOP VIEW С 0.10 0.15 0.25 A2 D 1.55 1.60 1.65 E 1.50 1.60 1.70 E1 0.70 0.80 0.90 С 1.00 BSC е SEATING Ċ A1 L 0.20 PLANE 0.10 0.15 -0.356 END VIEW SIDE VIEW GENERIC **MARKING DIAGRAM\*** 1.803 0.787XXM XX = Specific Device Code Μ = Date Code 0.508 = Pb-Free Package 1.000 \*This information is generic. Please refer to device data sheet for actual part marking. RECOMMENDED MOUNTING FOOTPRINT\* Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY not follow the Generic Marking. AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES STYLE 3: PIN 1. ANODE 2. ANODE STYLE 1: PIN 1. BASE 2. EMITTER STYLE 2: PIN 1. ANODE 2. N/C REFERENCE MANUAL, SOLDERRM/D. 3. COLLECTOR 3. CATHODE 3. CATHODE STYLE 4: STYLE 5: PIN 1. CATHODE 2. CATHODE PIN 1. GATE 2. SOURCE 3. ANODE 3. DRAIN Electronic versions are uncontrolled except when accessed directly from the Document Repository. DOCUMENT NUMBER: 98ASB15184C Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DESCRIPTION:** SC75-3 1.60x0.80x0.80, 1.00P PAGE 1 OF 1 onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

# Onsem





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DESCRIPTION:	SOT-1123 0.80x0.60x0.37, 0.35P		PAGE 1 OF 1

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### **MECHANICAL CASE OUTLINE** PACKAGE DIMENSIONS



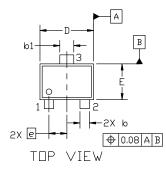
#### SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

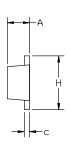
### DATE 24 JAN 2024

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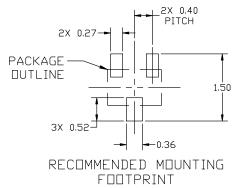
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSION: MILLIMETERS. 1.
- 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH, MINIMUM З. LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.



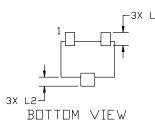


SIDE VIEW

	MILLIMETERS				
DIM	MIN.	NDM.	MAX.		
А	0.45	0.50	0.55		
b	0.15	0.21	0.27		
b1	0.25	0.31	0.37		
С	0.07	0.12	0.17		
D	1.15	1.20	1.25		
E	0.75	0.80	0.85		
e		0.40 BSC			
Н	1.15	1.20	1.25		
L	0.29 REF				
L2	0.15	0.20	0.25		



\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.



GENERIC **MARKING DIAGRAM\*** 



XX = Specific Device Code Μ = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE	STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 4: PIN 1. CATH 2. CATH 3. ANOE	ODE 2. SOURCE			
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DESCRIPTION: SOT-723 1.20x0.80x0.50, 0						PAGE 1	OF 1
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